

Product Overview

FGAF20N60SMD: IGBT, 600V, 20A, Field Stop

For complete documentation, see the data sheet.

Using novel field stop IGBT technology, ON Semiconductor's new series of field stop 2nd generation IGBTs offer the optimum performance for consumer appliances, motion control and home appliances where low conduction and switching losses are essential.

Features

- Maximum junction temperature : $T_J = 175^\circ\text{C}$
- Positive temperature co-efficient for easy parallel operating
- High current capability
- Low saturation voltage: $V_{CE(sat)} = 1.7\text{V(Typ.) @ } I_C = 20\text{A}$
- High input impedance
- Fast switching: $E_{OFF} = 7\mu\text{J/A}$
- Tightened parameter distribution
- RoHS compliant

Applications

- Consumer Appliances
- Motion Control - Home Appliance

Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	$V_{(BR)CES}$ Typ (V)	I_C Max (A)	$V_{CE(sat)}$ Typ (V)	V_F Typ (V)	E_{off} Typ (mJ)	E_{on} Typ (mJ)	T_{rr} Typ (ns)	I_{rr} Typ (A)	Gate Charge Typ (nC)	Short Circuit Withstand (μs)	E_{AS} Typ (mJ)	P_D Max (W)	Co-Packaged Diode	Package Type
FGAF20N60SMD	1.9	Pb-free non AEC-Q and PPAP	Active	600	20	1.7	2.3	0.141	0.452	88.2	-	64	-	-	75	Yes	TO-3PF-3L

For more information please contact your local sales support at www.onsemi.com.

Created on: 1/28/2021